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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No. 10/072,415
 Filing Date February 5, 2002
 Inventor Ji Ung Lee et al.
 Assignee Micron Technology, Inc.
 Group Art Unit 2891
 Examiner Steven J. Fulk
 Confirmation No. 5182
 Customer No. 021567
 Attorney's Docket No. MI30-068
 Title: Field Effect Transistor Fabrication Methods, Field Emission Device Fabrication
 Methods, and Field Emission Device Operational Methods

RESPONSE TO AUGUST 8, 2006 OFFICE ACTION

To: Mail Stop Amendment
 Assistant Commissioner for Patents
 P.O. Box 1450
 Alexandria VA 22313-1450

From: James D. Shaurette (Tel. 509-624-4276; Fax 509-838-3424)
 Wells, St. John, P.S.
 601 W. First Avenue, Suite 1300
 Spokane, WA 99201-3828

Sir:

Responsive to the Office Action dated August 8, 2006, Applicants amend and
 remark as follows:

AMENDMENTS

01/11/2007 EFLORES 00000001 230925 10072415

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